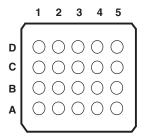
8-BIT BIDIRECTIONAL VOLTAGE-LEVEL TRANSLATOR FOR OPEN-DRAIN AND PUSH-PULL APPLICATIONS

FEATURES

- No Direction-Control Signal Needed
- Max Data Rates
 - 60 Mbps (Push Pull)
 - 2 Mbps (Open Drain)
- 1.2 V to 3.6 V on A Port and 1.65 V to 5.5 V on B Port (V_{CCA} ≤ V_{CCB})
- No Power-Supply Sequencing Required Either V_{CCA} or V_{CCB} Can Be Ramped First
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22 (A Port)
 - 2000-V Human-Body Model (A114-B)
 - 150-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

- IEC 61000-4-2 ESD (B Port)
 - ±8-kV Contact Discharge
 - ±6-kV Air-Gap Discharge

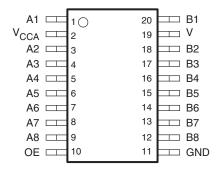
ZXY PACKAGE (BOTTOM VIEW)



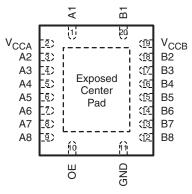
TERMINAL ASSIGNMENTS

	1	2	3	4	5
D	V _{CCB}	B2	B4	В6	B8
С	B1	В3	B5	В7	GND
В	A1	А3	A5	A7	OE
Α	V _{CCA}	A2	A4	A6	A8

PW PACKAGE (TOP VIEW)



RGY PACKAGE (TOP VIEW)



The exposed center pad, if used, must be connected as a secondary ground or left electrically open.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



DESCRIPTION/ORDERING INFORMATION

This 8-bit noninverting translator uses two separate configurable power-supply rails. The A port is designed to track V_{CCA} . V_{CCA} accepts any supply voltage from 1.2 V to 3.6 V. The B port is designed to track V_{CCB} . V_{CCB} accepts any supply voltage from 1.65 V to 5.5 V. This allows for low-voltage bidirectional translation between any of the 1.2-V, 1.5-V, 1.8-V, 2.5-V, 3.3-V, and 5-V voltage nodes.

When the output-enable (OE) input is low, all outputs are placed in the high-impedance state.

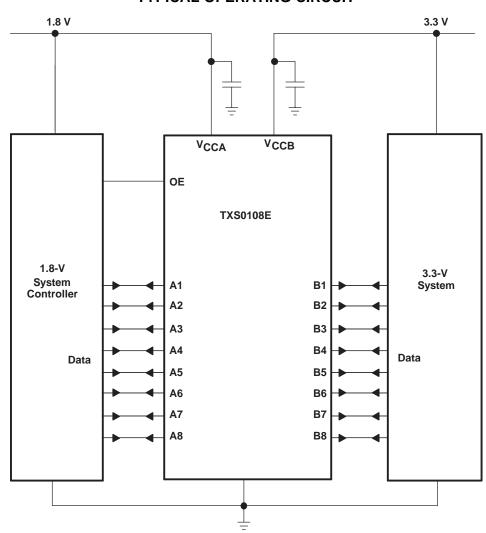
To ensure the high-impedance state during power up or power down, OE should be tied to GND through a pulldown resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

ORDERING INFORMATION

T _A	PACKAGE ⁽¹⁾⁽²⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING
	QFN – RGY	Reel of 1000	TXS0108ERGYR	YF08E
-40°C to 85°C	TSSOP – PW	Reel of 2000	TXS0108EPWR	YF08E
	UFBGA – ZXY	Reel of 2500	TXS0108EZXYR	YF08E

- (1) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.
- (2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

TYPICAL OPERATING CIRCUIT



ABSOLUTE MAXIMUM RATINGS(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CCA}	Supply valtage range		-0.5	4.6	V
V_{CCB}	Supply voltage range Input voltage range (2) Voltage range applied to any output in the high-impedance or power-off state (2) Voltage range applied to any output in the high or low state (2)(3) Input clamp current Output clamp current Continuous output current Continuous current through V _{CCA} , V _{CCB} , or GND Storage temperature range		-0.5	5.5	V
V	Input voltage range (2)	A port	-0.5	4.6	V
VI	input voltage range -/	B port	-0.5	6.5	V
V	Voltage range applied to any output	A port	-0.5	4.6	V
Vo	in the high-impedance or power-off state (2)	B port	-0.5	4.6 5.5 4.6 6.5 4.6 6.5	V
\/	Voltage and the day of the bight of the color of the (2)(3)	A port	-0.5	V _{CCA} + 0.5	V
Vo	voltage range applied to any output in the high or low state	B port	-0.5	V _{CCB} + 0.5	V
I _{IK}	Input clamp current	V _I < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current			±50	mA
	Continuous current through V _{CCA} , V _{CCB} , or GND			±100	mA
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

THERMAL IMPEDANCE RATINGS

				UNIT
		PW package ⁽¹⁾	70	
θ_{JA}	Package thermal impedance	RGY package (2)	80.9	°C/W
		ZXY package ⁽¹⁾	47	

⁽¹⁾ The package thermal impedance is calculated in accordance with JESD 51-5.

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⁽²⁾ The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

⁽³⁾ The value of V_{CCA} and V_{CCB} are provided in the recommended operating conditions table.

⁽²⁾ The package thermal impedance is calculated in accordance with JESD 51-7.



RECOMMENDED OPERATING CONDITIONS(1)(2)

			V _{CCA}	V _{CCB}	MIN	MAX	UNIT
V_{CCA}	Supply voltage ⁽³⁾				1.2	3.6	V
V _{CCB}	Supply Voltage (7)				1.65	5.5	V
		A-Port I/Os	1.2 V to 1.95 V	1.65 V to 5.5 V	V _{CCI} - 0.2	V_{CCI}	
V	Lligh lovel input voltage	A-POIL I/OS	1.95 V to 3.6 V	1.65 V 10 5.5 V	V _{CCI} - 0.4	V_{CCI}	V
V _{IH}	High-level input voltage	B-Port I/Os	1.2 V to 3.6 V	1.65 V to 5.5 V	V _{CCI} - 0.4	V_{CCI}	V
		OE	1.2 V 10 3.6 V	1.05 V 10 5.5 V	V _{CCA} × 0.65	5.5	
		A-Port I/Os	1.2 V to 1.95 V	1 65 \/ to 5 5 \/	0	0.15	
V	Low-level input voltage	A-POIL I/OS	1.95 V to 3.6 V	1.65 V to 5.5 V	0	0.15	V
V_{IL}	Low-level input voltage	B-Port I/Os	4.0.1/40.0.1/	4.05.1/+- 5.5.1/	0		
		OE	1.2 V to 3.6 V	1.65 V to 5.5 V	0	V _{CCA} × 0.35	
		A-Port I/Os push-pull driving					
Δt/Δν	Input transition rise or fall rate	B-Port I/Os push-pull driving	1.2 V to 3.6 V	1.65 V to 5.5 V		10	ns/V
		Control input					
T _A	Operating free-air temperature				-40	85	°C

 $[\]begin{array}{lll} \hbox{(1)} & V_{CCI} \ \hbox{is the} \ V_{CC} \ \hbox{associated with the data input port.} \\ \hbox{(2)} & V_{CCO} \ \hbox{is the} \ V_{CC} \ \hbox{associated with the output port.} \\ \hbox{(3)} & V_{CCA} \ \hbox{must be less than or equal to} \ V_{CCB}, \ \hbox{and} \ V_{CCA} \ \hbox{must not exceed 3.6 V.} \\ \end{array}$

ELECTRICAL CHARACTERISTICS (1)(2)(3)

over recommended operating free-air temperature range (unless otherwise noted)

DA	RAMETER	TEST	V	V.		$T_A = 25^{\circ}C$		-40°C to 8	5°C	UNIT
PA	RANETER	CONDITIONS	V _{CCA}	V _{CCB}	MIN	TYP	MAX	MIN	MAX	UNII
\/		$I_{OH} = -20 \mu A$,	1.2 V	1.65 V to 5.5 V		V _{CCA} × 0.67				V
V _{OHA}		$V_{IB} \ge V_{CCB} - 0.4 \text{ V}$	1.4 V to 3.6 V	1.03 V to 3.3 V				$V_{CCA} \times 0.67$		V
		$I_{OL} = 135 \mu A,$ $V_{IB} \le 0.15 V$	1.2 V				0.25			
		$I_{OL} = 180 \mu A,$ $V_{IB} \le 0.15 V$	1.4 V						0.4	
V_{OLA}		$I_{OL} = 220 \mu A,$ $V_{IB} \le 0.15 \text{ V}$	1.65 V	1.65 V to 5.5 V					0.4	V
		$I_{OL} = 300 \mu A,$ $V_{IB} \le 0.15 \text{ V}$	2.3 V						0.4	
		$I_{OL} = 400 \mu A,$ $V_{IB} \le 0.15 V$	3 V						0.55	
V _{OHB}		$I_{OH} = -20 \mu A$,	1.2 V	1.65 V to 5.5 V						V
* OHB		$V_{IA} \ge V_{CCA} - 0.2 \text{ V}$	1.4 V to 3.6 V	1.00 1 10 0.0 1				V _{CCB} × 0.67		v
		$I_{OL} = 220 \mu A,$ $V_{IA} \le 0.15 \text{ V}$		1.65 V					0.4	
V _{OLB}		$I_{OL} = 300 \ \mu A,$ $V_{IA} \le 0.15 \ V$	1.2 V to 3.6 V	2.3 V					0.4	V
VOLB		$I_{OL} = 400 \mu A,$ $V_{IA} \le 0.15 \text{ V}$	1.2 V to 3.0 V	3 V					0.55	V
		$I_{OL} = 620 \mu A,$ $V_{IA} \le 0.15 \text{ V}$		4.5 V					0.55	
l _l	OE	$V_I = V_{CCI}$ or GND	1.2 V	1.65 V to 5.5 V			±1		2	μΑ
oz	A or B port		1.2 V	1.65 V to 5.5 V			±1		±2	μΑ
			1.2 V	1.65 V to 5.5 V		1.5			±2	
		$V_I = V_O = Open,$	1.4 V to 3.6 V	2.3 V to 5.5 V					2	μА
CCA		$I_0 = 0$	3.6 V	0 V					2	μΛ
			0 V	5.5 V					-1	
			1.2 V	1.65 V to 5.5 V		1.5				
		$V_I = V_O = Open,$	1.4 V to 3.6 V	2.3 V to 5.5 V					6	
CCB		$I_{O} = 0$	3.6 V	0 V					-1	μΑ
			0 V	5.5 V					1	
	1	$V_I = V_{CCI}$ or GND,	1.2 V	2.3 V to 5.5 V		3				
CCA +	ICCB	$I_{O} = 0$	1.4 V to 3.6 V	2.3 V 10 5.5 V					8	μΑ
		$V_I = V_O = Open,$	1.2 V	4.05.1/4- 5.5.1/		0.05				
CCZA		$I_0 = 0$, OE = GND	1.4 V to 3.6 V	1.65 V to 5.5 V					2	μА
		$V_I = V_O = Open,$	1.2 V	4.05.1/: 5.5.1		4				
CCZB		$I_O = 0$, OE = GND	1.4 V to 3.6 V	1.65 V to 5.5 V					6	μΑ
C _i	OE		3.3 V	3.3 V		4.5			5.5	pF
	A port		0.01/	2.21/		6			7	
C_{io}	B port		3.3 V	3.3 V		5.5			6	pF

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 $[\]begin{array}{ll} \text{(1)} & \text{V_{CCO} is the V_{CC} associated with the output port.} \\ \text{(2)} & \text{V_{CCI} is the V_{CC} associated with the input port.} \\ \text{(3)} & \text{V_{CCA} must be less than or equal to V_{CCB}, and V_{CCA} must not exceed 3.6 V.} \\ \end{array}$



TIMING REQUIREMENTS

 $T_A=25^{\circ}C, V_{CCA} = 1.2 \text{ V}$

				V _{CCB} = 1.8 V	V _{CCB} = 2.5 V	V _{CCB} = 3.3 V	V _{CCB} = 5 V	LINUT	
				TYP	TYP	TYP	TYP	UNII	
	Push-pull driving			20	20	20	20	Mbna	
	Data rate	Open-drain driving		2	2	2	TYP TYP 20 20 Mbps 50 50 ns	IVIDPS	
	Push-pull driving		Data innuta	50	50	50	50	20	
ı _w	Pulse duration	Open-drain driving Data inputs		500	500	500	500	ns	

TIMING REQUIREMENTS

over recommended operating free-air temperature range, $V_{CCA} = 1.5 \text{ V} \pm 0.1 \text{ V}$ (unless otherwise noted)

				V _{CCB} = ± 0.1		V _{CCB} = ± 0.2		V _{CCB} = ± 0.3		V _{CCB} = ± 0.5		UNIT
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
	Data rate	Push-pull driving			40		60		60		50	Mbps
		Open-drain driving			2		2		2		2	IVIDPS
t _w	Dulas duration	Push-pull driving	Data innuta	25		16.7		16.7		20		20
	Pulse duration	Open-drain driving	Data inputs	500		500		500		500		ns

TIMING REQUIREMENTS

over recommended operating free-air temperature range, $V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V}$ (unless otherwise noted)

				V _{CCB} = 0.15	1.8 V 5 V	V _{CCB} = 2 ± 0.2		V _{CCB} = 3 ± 0.3		V _{CCB} = 5 V ± 0.5 V		UNIT
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
	Data rate Push-pull driving			40		60		60		60	Mbps	
		Open-drain driving			2		2		2		2	MDPS
t_{w}	Pulse duration	Push-pull driving	Data innuta	25		16.7		16.7		16.7		20
	Pulse duration	Open-drain driving	Data inputs	500		500		500		500		ns

TIMING REQUIREMENTS

over recommended operating free-air temperature range, $V_{CCA} = 2.5 \text{ V} \pm 0.2 \text{ V}$ (unless otherwise noted)

				V _{CCB} = 2 ± 0.2 \		V _{CCB} = 3 ± 0.3		V _{CC} = 9 ± 0.5		UNIT
				MIN	MAX	MIN	MAX	MIN	MAX	
	Data rata	Push-pull driving			60		60		60	Maria
	Data rate	Open-drain driving			2		2		2	Mbps
	Dulas duration	Push-pull driving	Data inputa	16.7		16.7		16.7		20
ι _w	Pulse duration	Open-drain driving	Data inputs	500		500		500		ns

TIMING REQUIREMENTS

over recommended operating free-air temperature range, $V_{CCA} = 3.3 \text{ V} \pm 0.3 \text{ V}$ (unless otherwise noted)

				V _{CCB} = 3 ± 0.3		V _{CC} = 5 ± 0.5		UNIT
				MIN	MAX	MIN	MAX	
	Data rate Push-pull driving				60		60	Mbps
	Data fate	Open-drain driving			2		2	IVIDPS
	Dulas duration	Push-pull driving	ush-pull driving			16.7		20
t _w Pulse duration	Open-drain driving	Data inputs	500		500		ns	

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $V_{CCA} = 1.2 \text{ V}$ (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	V _{CCB} = 1.8 V ± 0.15 V	V _{CCB} = 2.5 V ± 0.2 V	V _{CCB} = 3.3 V ± 0.3 V	V _{CCB} = 5 V ± 0.5 V	UNIT
	(INPUT)	(001701)	CONDITIONS	TYP	TYP	TYP		
			Push-pull driving	6.5	5.9	5.7	5.5	
t _{PHL}	Α	В	Open-drain driving	11.9	11.1	11.0	11.1	
4	A	Б	Push-pull driving	7.1	6.3	6.2	6.6	ns
t _{PLH}			Open-drain driving	293	236	197	152	
			Push-pull driving	6.4	6	5.8	5.6	
t _{PHL}	В	А	Open-drain driving	8.5	6.8	6.2	5.9	
	В	A	Push-pull driving	5.6	4.1	3.6	3.2	ns
t _{PLH}			Open-drain driving	312	248	192	132	
t _{en}	OE	A or B	Push-pull driving	200	200	200	200	ns
t _{dis}	OE	A or B	Push-pull driving	16.8	13.9	13.2	13.5	ns
	A nor	t rice time	Push-pull driving	7.9	6.7	6.5	6.4	20
t_{rA}	A-por	t rise time	Open-drain driving	296	238	185	127	ns
	P nor	t rise time	Push-pull driving	6.3	3.3	1.8	1.5	20
t_{rB}	Б-рог	t iise tiiiie	Open-drain driving	236	164	115	60	ns
	A 200	rt fall time	Push-pull driving	5.8	4.8	4.3	3.8	
t_fA	А-ро	it iall lille	Open-drain driving	5.9	4.7	4.1	3.5	20
	Pino	rt fall time	Push-pull driving	4.6	2.8	2.2	1.9	ns
t_fB	Б- роі	it iall lille	Open-drain driving	4.5	2.7	2.2	1.9	
t _{SK(O)}		el-to-channel skew	Push-pull driving	1	1	1	1	ns
May data rete	,	l or D	Push-pull driving	20	20	20	20	Mbn-
Max data rate		A or B	Open-drain driving	2	2	2	2	Mbps

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SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $V_{CCA} = 1.5 \text{ V} \pm 0.1 \text{ V}$ (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	V _{CCB} = ± 0.15		V _{CCB} = ± 0.2		V _{CCB} = 3 ± 0.3		V _{CCB} = ± 0.5		UNIT	
	(INFUT)	(001701)	CONDITIONS	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX		
			Push-pull driving		11		9.2		8.6		8.6		
t _{PHL}	٨	В	Open-drain driving	4	14.4	3.6	12.8	3.5	12.2	3.5	12	ns	
t _{PLH} A		Ь	Push-pull driving		12		10		9.8		9.7	115	
			Open-drain driving	182	720	143	554	114	473	81	384		
			Push-pull driving		12.7		11.1		11		12		
t _{PHL}	В	Α	Open-drain driving	3.4	13.2	3.1	9.6	2.8	8.5	2.5	7.5		
	A	Push-pull driving		9.5		6.2		5.1		1.6	ns		
t _{PLH}			Open-drain driving	186	745	147	603	118	519	84	407		
t _{en}	OE	A or B	Push-pull driving		200		200		200		200	ns	
t _{dis}	OE	A or B	Push-pull anving		28.1		22		20.1		19.6	ns	
	A nort	riaa tima	Push-pull driving	3.5	13.1	3	9.8	3.1	9	3.2	8.3		
t _{rA}	A-port	rise time	Open-drain driving	147	982	115	716	92	592	66	481	ns	
	P port	rise time	Push-pull driving	2.9	11.4	1.9	7.4	0.9	4.7	0.7	2.6	no	
t _{rB}	Б-роп	lise unie	Open-drain driving	135	1020	91	756	58	653	20	370	ns	
	A nom	t fall time	Push-pull driving	2.3	9.9	1.7	7.7	1.6	6.8	1.7	6		
t_fA	A-por	t fall time	Open-drain driving	2.4	10	2.1	7.9	1.7	7	1.5	6.2	no	
4	Phon	t fall time	Push-pull driving	2	8.7	1.3	5.5	0.9	3.8	0.8	3.1	ns	
t _{fB}	Б- рог	ı iali tillie	Open-drain driving	1.2	11.5	1.3	8.6	1	9.6	0.5	7.7		
t _{SK(O)}		-to-channel kew	Push-pull driving		1	1	1		1.1		1	ns	
Max data rate	^	or P	Push-pull driving	40		60		60		50		Mb	
iviax data rate	А	or B	Open-drain driving	2		2		2		2		s	

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V} \text{(unless otherwise noted)}$

PARAMETER	FROM	то	TEST	V _{CCB} = 1 ± 0.15		V _{CCB} = 2 ± 0.2		V _{CCB} = ± 0.3		V _{CCB} = ± 0.5	5 V V	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CONDITIONS	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MA X	0
			Push-pull driving		8.2		6.4		5.7		5.6	
t _{PHL}	A	В	Open-drain driving	3.6	11.4	3.2	9.9	3.1	9.3	3.1	8.9	
	t _{PLH}	Б	Push-pull driving		9		2.1		6.5		6.3	ns
ЧРLН			Open-drain driving	194	729	155	584	126	466	90	346	
	t _{PHL}		Push-pull driving		9.8		8		7.4		7	
^l PHL		٨	Open-drain driving	3.4	12.1	2.8	8.5	2.5	7.3	2.1	6.2	
	В А	Push-pull driving		10.2		7		5.8		5	ns	
t _{PLH}	PLH		Open-drain driving	197	733	159	578	129	459	93	323	
t _{en}	OE	A or B	Push-pull driving		200		200		200		200	ns
t _{dis}	OE	A or B	Push-pull driving		25.1		18.8		16.5		15.3	ns
	۸	-1 41	Push-pull driving	3.1	11.9	2.6	8.6	2.7	7.8	2.8	7.2	
t _{rA}	A-pon	rise time	Open-drain driving	155	996	124	691	100	508	72	350	ns
	D	-141	Push-pull driving	2.8	10.5	1.8	7.2	1.2	5.2	0.7	2.7	
t _{rB}	B-pon	rise time	Open-drain driving	132	1001	106	677	73	546	32	323	ns
	A nor	t fall time	Push-pull driving	2.1	8.8	1.6	6.6	1.4	5.7	1.4	4.9	
t _{fA}	A-por	t fall time	Open-drain driving	2.2	9	1.7	6.7	1.4	5.8	1.2	5.2	
	D	t fall time	Push-pull driving	2	8.3	1.3	5.4	0.9	3.9	0.7	3	ns
t _{fB}	B-por	t fall time	Open-drain driving	0.8	10.5	0.7	10.7	1	9.6	0.6	7.8	
t _{SK(O)}	Channel-to	-channel skew	Push-pull driving		1		1		1		1	ns
May data ret-		or D	Push-pull driving	40		60		60		60		Mhna
Max data rate	A	or B	Open-drain driving	2		2		2		2		Mbps



SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $V_{CCA} = 2.5 \text{ V} \pm 0.2 \text{ V}$ (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	V _{CCB} = 2 ± 0.2		V _{CCB} = 3 ± 0.3		V _{CCB} = ± 0.5		UNIT	
	(INFUT)	(001701)	CONDITIONS	MIN	MAX	MIN	MAX	MIN	MAX		
			Push-pull driving		5		4		3.7		
t _{PHL}	Α	В	Open-drain driving	2.4	6.9	2.3	6.3	2.2	5.8	ns	
	A	В	Push-pull driving		5.2		4.3		3.9	115	
t _{PLH}			Open-drain driving	149	592	125	488	93	368		
			Push-pull driving		5.4		4.7		4.2		
lPHL	B A	Open-drain driving	2.5	7.3	2.2	6	1.8	4.9			
		A	Push-pull driving		5.9		4.4		3.5	ns	
t _{PLH}			Open-drain driving	150	595	126	481	94	345		
t _{en}	OE	A or B	Duch hull driving		200		200		200	ns	
t _{dis}	OE	A or B	Push-pull driving		15.7		12.9		11.2	ns	
			Push-pull driving	2	7.3	2.1	6.4	2.2	5.8		
t _{rA}	А-рог	t rise time	Open-drain driving	110	692	93	529	68	369	ns	
	Dinar	t riag time	Push-pull driving	1.8	6.5	1.3	5.1	0.7	3.4		
t _{rB}	Б-рог	t rise time	Open-drain driving	107	693	79	483	41	304	ns	
	Λ 200	rt fall time	Push-pull driving	1.5	5.7	1.2	4.7	1.3	3.8		
t _{fA}	A-poi	rt fall time	Open-drain driving	1.5	5.6	1.2	4.7	1.1	4		
	D no	rt fall time	Push-pull driving	1.4	5.4	0.9	4.1	0.7	3	ns	
t _{fB}	D- poi	rt fall time	Open-drain driving	0.4	14.2	0.5	19.4	0.4	3		
t _{SK(O)}	Channel-to	o-channel skew	Push-pull driving		1		1.2		1	ns	
Many data as t	,	D	Push-pull driving	60		60		60			
Max data rate	F	A or B	Open-drain driving	2		2		2		Mbps	

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $V_{CCA} = 3.3 \text{ V} \pm 0.3 \text{ V}$ (unless otherwise noted)

PARAMETER	FROM	TO	TEST	V _{CCB} = 3 ± 0.3	3.3 V V	V _{CCB} = ± 0.5	5 V V	UNIT	
	(INPUT)	(OUTPUT)	CONDITIONS	MIN	MAX	MIN	MAX		
			Push-pull driving		3.8		3.1		
t _{PHL}	^	Б	Open-drain driving	2	5.3	1.9	4.8		
	Α	В	Push-pull driving		3.9		3.5	ns	
t _{PLH}			Open-drain driving	111	439	87	352		
			Push-pull driving		4.2		3.8		
t _{PHL}	В		Open-drain driving	2.1	5.5	1.7	4.5		
	В	Α	Push-pull driving		3.8		4.3	ns	
t _{PLH}			Open-drain driving	112	449	86	339		
t _{en}	OE	A or B	Durah multi dati da a		200		200	ns	
t _{dis}	OE	A or B	Push-pull driving		11.9		9.8	ns	
4	A at	win n 4:	Push-pull driving	1.8	5.7	1.9	5		
t _{rA}	А-роп	rise time	Open-drain driving	75	446	57	337	ns	
4	D = ===	win n 4imm n	Push-pull driving	1.5	5	1	3.6		
t _{rB}	в-роп	rise time	Open-drain driving	72	427	40	290	ns	
4	Δ	t fall time a	Push-pull driving	1.2	4.5	1.1	3.5		
t _{fA}	A-pon	t fall time	Open-drain driving	1.1	4.4	1	3.7		
4	D	t fall time a	Push-pull driving	1.1	4.2	0.8	3.1	ns	
t _{fB}	в-роп	t fall time	Open-drain driving	1	4.2	0.8	3.1		
t _{SK(O)}	Channel-to-	-channel skew	Push-pull driving		1		1	ns	
	Δ.	D	Push-pull driving	60		60			
Max data rate	A or B		Open-drain driving	2		2		Mbps	

OPERATING CHARACTERISTICS

 $T_A=25$ °C

						V _{CCA}							
			1.2 V	1.2 V	1.5 V	1.8 V	2.5 V	2.5 V	3.3 V				
PARAMETER		TEST CONDITIONS				V _{CCB}				UNIT			
			5 V	1.8 V	1.8 V	1.8 V	2.5 V	5 V	3.3 V to 5 V				
			TYP	TYP	TYP	TYP	TYP	TYP	TYP				
<u> </u>	A-port input, B-port output		5.9	5.7	5.9	5.9	6.7	6.9	8				
C _{pdA}	B-port input, A-port output	$\begin{split} &C_L = 0, f = 10 \text{ MHz}, \\ &t_{f} = t_{f} = 1 \text{ns}, \\ &OE = V_{CCA} \\ &\text{(outputs enabled)} \end{split}$	10.2	10.3	9.9	9.7	9.7	9.4	9.8	pF			
0	A-port input, B-port output		29.9	22.2	21.5	20.8	21	23.4	23				
C _{pdB}	B-port input, A-port output		22.9	16.7	16.7	16.8	17.8	20.8	20.9				
	A-port input, B-port output		0.01	0.01	0.01	0.01	0.01	0.01	0.01				
C _{pdA}	B-port input, A-port output	$C_L = 0, f = 10 \text{ MHz}, t_f = t_f = 1 \text{ ns},$	0.06	0.01	0.01	0.01	0.01	0.01	0.01	n.E			
_	A-port input, B-port output	OE = GND (outputs disabled)	0.06	0.01	0.01	0.01	0.01	0.03	0.02	pF			
C _{pdB}	B-port input, A-port output		0.06	0.01	0.01	0.01	0.01	0.03	0.02				

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PRINCIPLES OF OPERATION

Applications

The TXS0108E can be used in level-translation applications for interfacing devices or systems operating at different interface voltages with one another. The TXS0108E is ideal for use in applications where an open-drain driver is connected to the data I/Os. The TXS0108E can also be used in applications where a push-pull driver is connected to the data I/Os, but the TXB0104 might be a better option for such push-pull applications. The TXS0108E device is a semi-buffered auto-direction-sensing voltage translator design is optimized for translation applications (e.g. MMC Card Interfaces) that require the system to start out in a low-speed open-drain mode and then switch to a higher speed push-pull mode.

Architecture

To address these application requirements, a semi-buffered architecture design is used and is illustrated below (see Figure 1). Edge-rate accelerator circuitry (for both the high-to-low and low-to-high edges), a High-Ron n-channel pass-gate transistor (on the order of 300 Ω to 500 Ω) and pull-up resistors (to provide DC-bias and drive capabilities) are included to realize this solution. A direction-control signal (to control the direction of data flow from A to B or from B to A) is not needed. The resulting implementation supports both low-speed open-drain operation as well as high-speed push-pull operation.

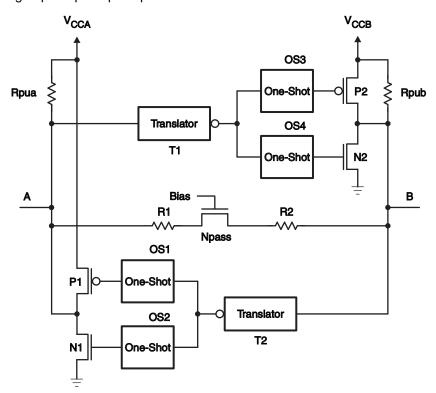


Figure 1. Architecture of a TXS01xx Cell

When transmitting data from A to B ports, during a rising edge the One-Shot (OS3) turns on the PMOS transistor (P2) for a short-duration and this speeds up the low-to-high transition. Similarly, during a falling edge, when transmitting data from A to B, the One-Shot (OS4) turns on NMOS transistor (N2) for a short-duration and this speeds up the high-to-low transition. The B-port edge-rate accelerator consists of one-shots OS3 and OS4, Transistors P2 and N2 and serves to rapidly force the B port high or low when a corresponding transition is detected on the A port.

When transmitting data from B to A ports, during a rising edge the One-Shot (OS1) turns on the PMOS transistor

(P1) for a short-duration and this speeds up the low-to-high transition. Similarly, during a falling edge, when transmitting data from B to A, the One-Shot (OS2) turns on NMOS transistor (N1) for a short-duration and this speeds up the high-to-low transition. The A-port edge-rate accelerator consists of one-shots OS1 and OS2, Transistors P1 and N1 components and form the edge-rate accelerator and serves to rapidly force the A port high or low when a corresponding transition is detected on the B port.

Power Up

During operation, ensure that $V_{CCA} \le V_{CCB}$ at all times. During power-up sequencing, $V_{CCA} \ge V_{CCB}$ does not damage the device, so any power supply can be ramped up first.

Enable and Disable

The TXS0108E has an OE input that is used to disable the device by setting OE low, which places all I/Os in the Hi-Z state. The disable time (t_{dis}) indicates the delay between the time when OE goes low and when the outputs actually get disabled (Hi-Z). The enable time (t_{en}) indicates the amount of time the user must allow for the one-shot circuitry to become operational after OE is taken high.

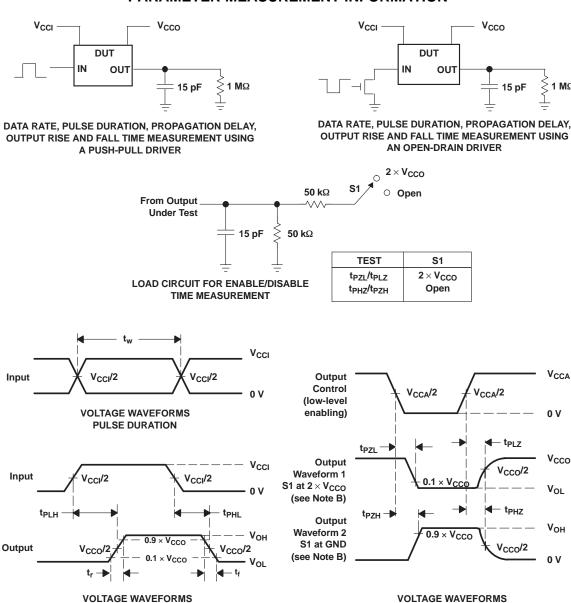
Pullup or Pulldown Resistors on I/O Lines

Each A-port I/O has a pull-up resistor (R_{pua}) to V_{CCA} and each B-port I/O has a pull-up resistor (R_{pub}) to V_{CCB} . R_{pua} and R_{pub} have a value of 40 k Ω when the output is driving low. R_{pua} and R_{pub} have a value of 4 k Ω when the output is driving high. R_{pua} and R_{pub} are disabled when OE = Low.

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PARAMETER MEASUREMENT INFORMATION



A. C_L includes probe and jig capacitance.

PROPAGATION DELAY TIMES

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_{Ω} = 50 Ω , $dv/dt \geq$ 1 V/ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en}.
- G. t_{PLH} and t_{PHL} are the same as t_{pd}.
- H. V_{CCI} is the V_{CC} associated with the input port.
- I. V_{CCO} is the V_{CC} associated with the output port.
- J. All parameters and waveforms are not applicable to all devices.

Figure 2. Load Circuit and Voltage Waveforms

ENABLE AND DISABLE TIMES

PACKAGE OPTION ADDENDUM

www.ti.com 31-Mar-2010

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TXS0108EPWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TXS0108EPWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TXS0108ERGYR	ACTIVE	VQFN	RGY	20	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TXS0108EZXYR	ACTIVE	BGA MI CROSTA R JUNI OR	ZXY	20	2500	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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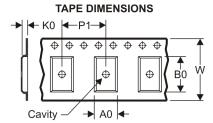
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PACKAGE MATERIALS INFORMATION

www.ti.com 5-May-2011

TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TXS0108EPWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
TXS0108ERGYR	VQFN	RGY	20	3000	330.0	12.4	3.8	4.8	1.6	8.0	12.0	Q1
TXS0108EZXYR	BGA MI CROSTA R JUNI OR	ZXY	20	2500	330.0	12.4	2.8	3.3	1.0	4.0	12.0	Q2

PACKAGE MATERIALS INFORMATION

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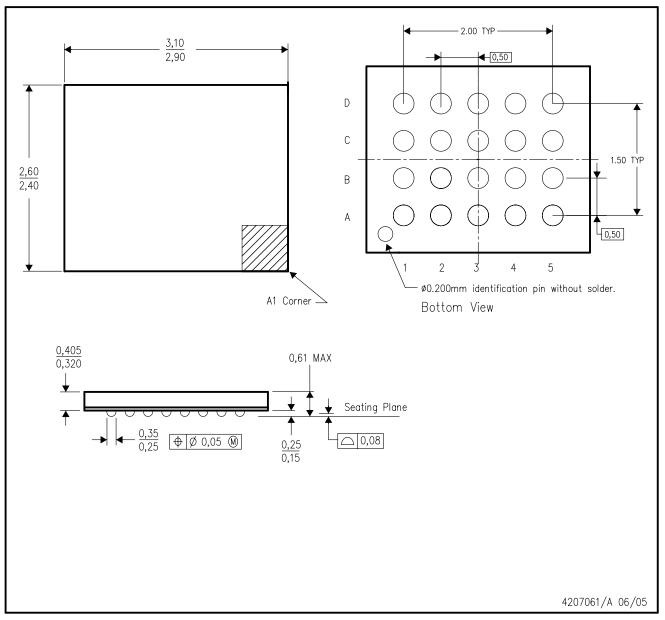


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TXS0108EPWR	TSSOP	PW	20	2000	346.0	346.0	33.0
TXS0108ERGYR	VQFN	RGY	20	3000	346.0	346.0	29.0
TXS0108EZXYR	BGA MICROSTAR JUNIOR	ZXY	20	2500	340.5	338.1	20.6

ZXY (S-PBGA-N20)

PLASTIC BALL GRID ARRAY



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. This package is a lead-free solder ball design.



PW (R-PDSO-G20)

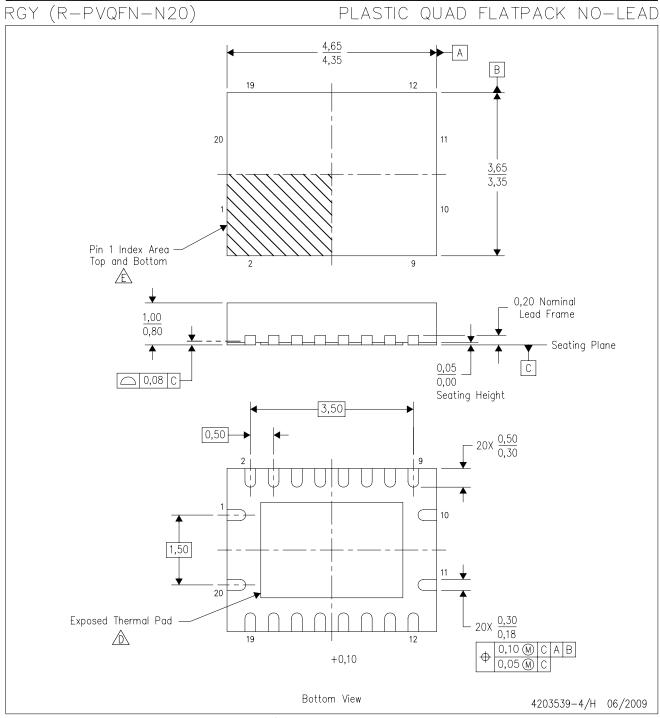
PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153





NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) package configuration.
- The package thermal pad must be soldered to the board for thermal and mechanical performance.

 See the Product Data Sheet for details regarding the exposed thermal pad dimensions.
- Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
- F. Package complies to JEDEC MO-241 variation BC.



RGY (R-PVQFN-N20)

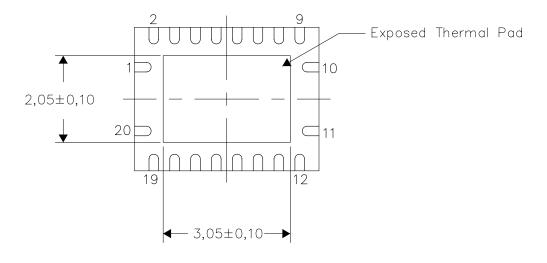
PLASTIC QUAD FLATPACK NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

Exposed Thermal Pad Dimensions

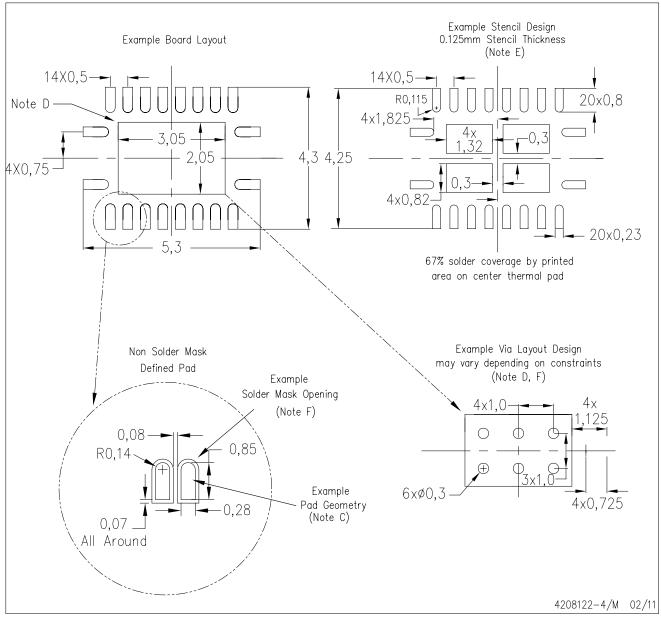
4206353-4/M 02/11

NOTE: A. All linear dimensions are in millimeters



RGY (R-PVQFN-N20)

PLASTIC QUAD FLATPACK NO-LEAD



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat—Pack QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com http://www.ti.com.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



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